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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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## DUAL HIGH CURRENT OPERATIONAL AMPLIFIER

### ■ GENERAL DESCRIPTION

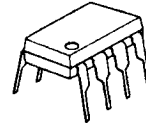
The NJM4556A integrated circuit is a high-gain, high output current dual operational amplifier capable of driving  $\pm 70\text{mA}$  into  $150\Omega$  loads ( $\pm 10.5\text{V}$  output voltage), and operating low supply voltage ( $V^+V^-=\pm 2\text{V}$ ).

The NJM4556A combines many of the features of the popular NJM4558 as well as having the capability of driving  $150\Omega$  loads. In addition, the wide band-width, low noise, high slew rate and low distortion of the NJM4556A make it ideal for many audio, telecommunications and instrumentation applications.

### ■ FEATURES

- Operating Voltage ( $\pm 2\text{V} \sim \pm 18\text{V}$ )
- High Output Current ( $I_o = 70\text{mA}$ )
- Slew Rate ( $3\text{V}/\mu\text{s}$  typ.)
- Gain Band Width Product ( $8\text{MHz}$  typ.)
- Equivalent Input Noise Voltage ( $10\text{nV}/\sqrt{\text{Hz}}$  typ.)
- Package Outline DIP8, DMP8, SIP8, SSOP8
- Bipolar Technology

### ■ PACKAGE OUTLINE



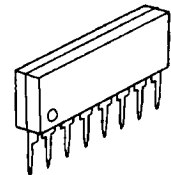
NJM4556AD



NJM4556AM

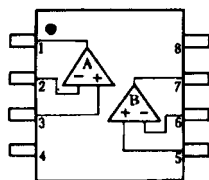


NJM4556AV

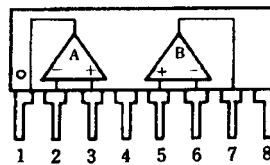


NJM4556AL

### ■ PIN CONFIGURATION



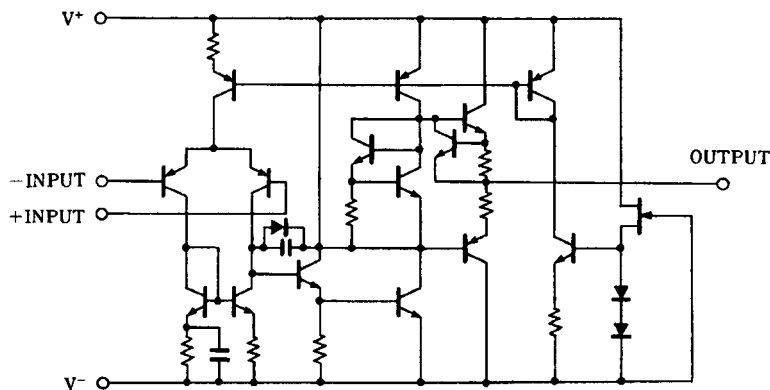
NJM4556AD  
NJM4556AM  
NJM4556AV



NJM4556AL

- PIN FUNCTION**
- 1. A OUTPUT
  - 2. A -INPUT
  - 3. A +INPUT
  - 4.  $V^-$
  - 5. B +INPUT
  - 6. B -INPUT
  - 7. B OUTPUT
  - 8.  $V^+$

### ■ EQUIVALENT CIRCUIT ( 1/2 Shown )



# NJM4556A

## ■ ABSOLUTE MAXIMUM RATINGS

( Ta=25°C )

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	$V^+ / V^-$	± 18	V
Differential Input Voltage	$V_{ID}$	± 30	V
Input Voltage	$V_{IC}$	± 15 ( note )	V
Power Dissipation	$P_D$	( DIP8 ) 700 ( DMP8 ) 300 ( SSOP8 ) 250 ( SIP8 ) 800	mW
Operating Temperature Range	$T_{opr}$	-40~+85	°C
Storage Temperature Range	$T_{stg}$	-40~+125	°C

( note ) For supply voltage less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

## ■ ELECTRICAL CHARACTERISTICS ( NJM4556AD / NJM4556AL )

(  $V^+ / V^- = \pm 15V, Ta = 25^\circ C$  )

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	$V_{IO}$	$R_S \leq 10k\Omega$	-	0.5	6.0	mV
Input Offset Current	$I_{IO}$		-	5	60	nA
Input Bias Current	$I_B$		-	50	500	nA
Input Resistance	$R_{IN}$		0.3	5	-	MΩ
Large Signal Voltage Gain	$A_V$	$R_L \geq 2k\Omega, V_O = \pm 10V$	86	100	-	dB
Maximum Output Voltage Swing 1	$V_{OM1}$	$R_L \geq 2k\Omega$	± 12	± 13.5	-	V
Maximum Output Voltage Swing 2	$V_{OM2}$	$R_L \geq 150\Omega$	± 10.5	± 11	-	V
Input Common Mode Voltage Range	$V_{ICM}$		± 13.5	± 14	-	V
Common Mode Rejection Ratio	CMR	$R_S \leq 10k\Omega$	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10k\Omega$	76.5	90	-	dB
Operating Current	$I_{CC}$		-	9	12	mA
Slew Rate	SR		-	3	-	V/μs
Gain Bandwidth Product	GB		-	8	-	MHz

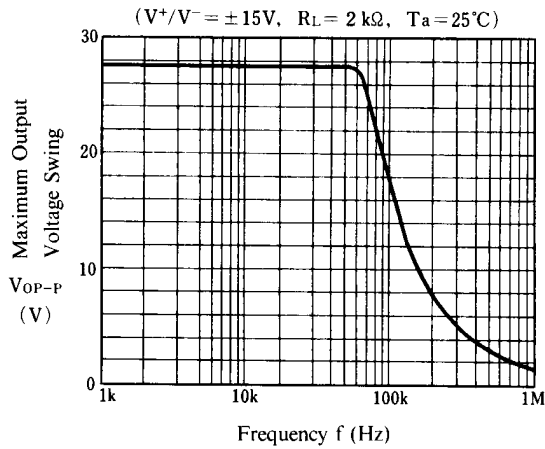
## ■ ELECTRICAL CHARACTERISTICS ( NJM4556AM / NJM4556AV )

(  $V^+ / V^- = \pm 15V, Ta = 25^\circ C$  )

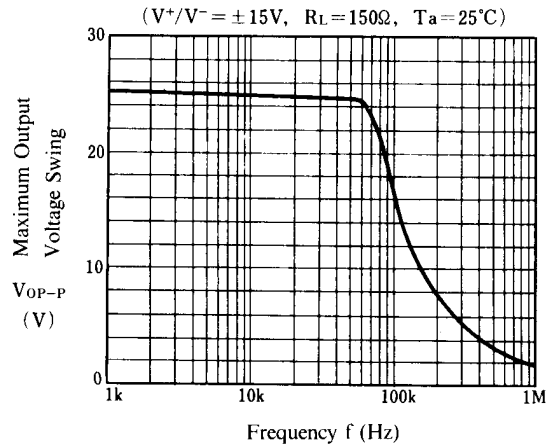
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Offset Voltage	$V_{IO}$	$R_S \leq 10k\Omega$	-	0.5	6.0	mV
Input Offset Current	$I_{IO}$		-	5	60	nA
Input Bias Current	$I_B$		-	50	500	nA
Large Signal Voltage Gain	$A_V$	$R_L \geq 2k\Omega, V_O = \pm 10V$	86	100	-	dB
Maximum Output Voltage Swing 1	$V_{OM1}$	$V_{IN}^+ = 4V, V_{IN}^- = 3V, V^+ = 9V, V^- = 0V$ $I_{SOURCE} = 40mA$	7.5	-	-	V
Maximum Output Voltage Swing 2	$V_{OM2}$	$V_{IN}^+ = 3V, V_{IN}^- = 4V, V^+ = 9V, V^- = 0V$ $I_{SINK} = 40mA$	-	-	2.1	V
Input Common Mode Voltage Range 1	$V_{ICM1}$	$V^+ = 9V, V^- = 0V, V_{IL}$	-	-	1.5	V
Input Common Mode Voltage Range 2	$V_{ICM2}$	$V^+ = 9V, V^- = 0V, V_{IH}$	8	-	-	V
Common Mode Rejection Ratio	CMR	$R_S \leq 10k\Omega$	70	90	-	dB
Supply Voltage Rejection Ratio	SVR	$R_S \leq 10k\Omega$	76.5	90	-	dB
Supply Current	$I_{CC}$	$V^+ = 9V, V^- = 0V$	-	8	12	mA
Slew Rate	SR		-	3	-	V/μs
Gain Bandwidth Product	GB		-	8	-	MHz

## ■ TYPICAL CHARACTERISTICS

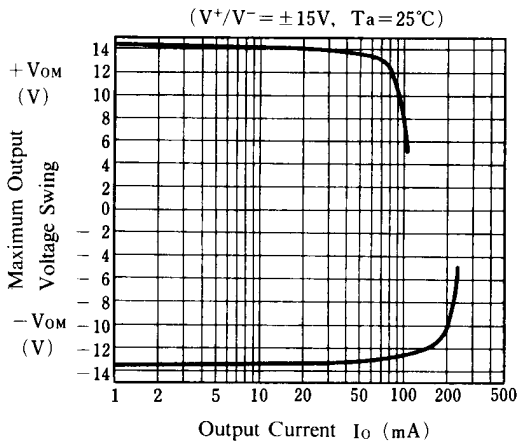
**Maximum Output Voltage Swing vs. Frequency**



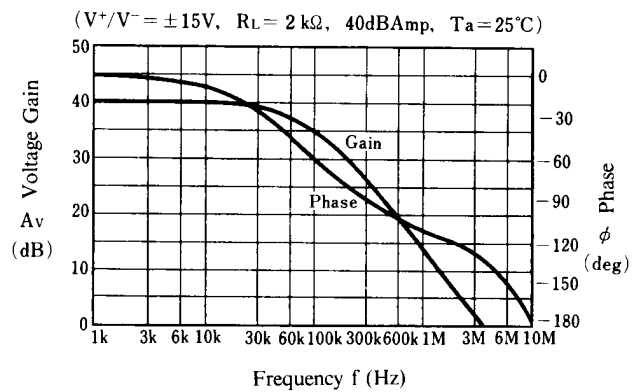
**Maximum Output Voltage Swing vs. Frequency**



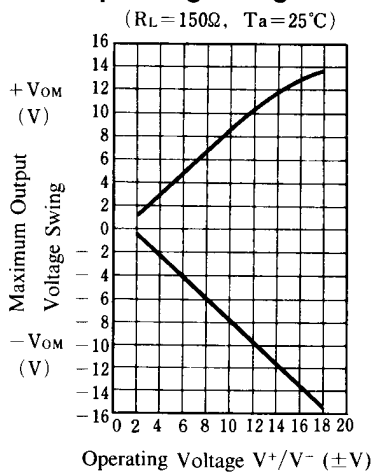
**Maximum Output Voltage Swing vs. Output Current**



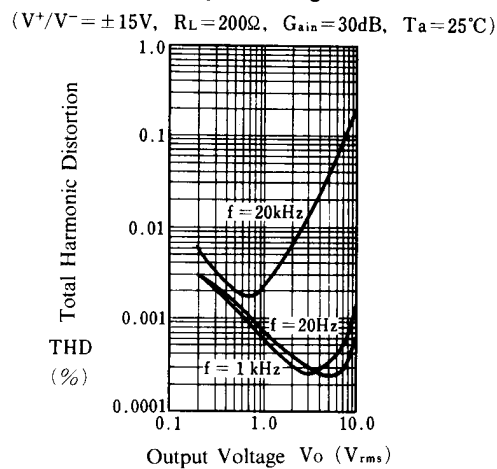
**Voltage Gain, Phase Shift vs. Frequency**



**Maximum Output Voltage Swing vs. Operating Voltage**



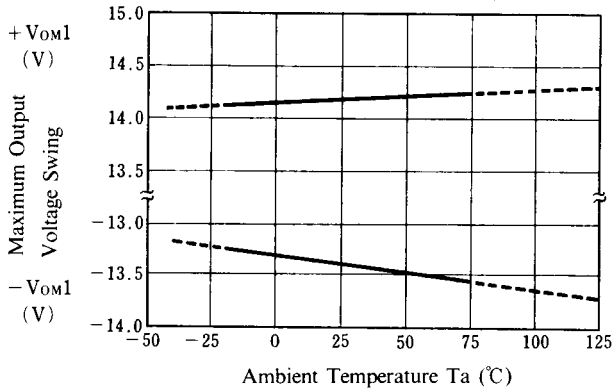
**Total Harmonic Distortion vs. Output Voltage**



## ■ TYPICAL CHARACTERISTICS

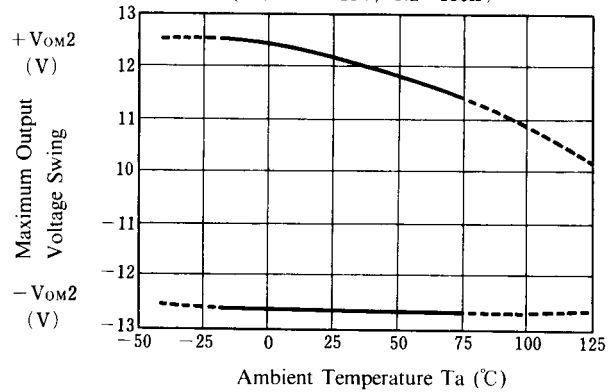
**Maximum Output Voltage Swing vs. Temperature**

( $V^+/V^- = \pm 15V$ ,  $R_L = 2\text{ k}\Omega$ )



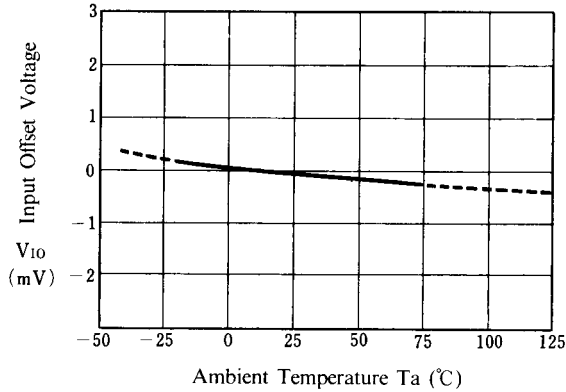
**Maximum Output Voltage Swing vs. Temperature**

( $V^+/V^- = \pm 15V$ ,  $R_L = 150\Omega$ )



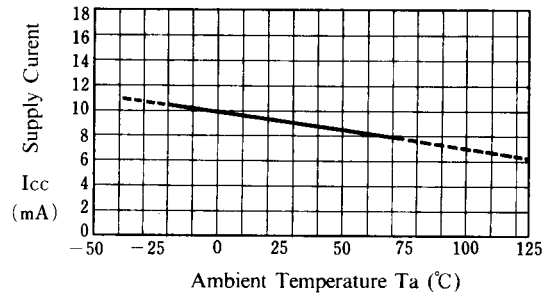
**Input Offset Voltage vs. Temperature**

( $V^+/V^- = \pm 15V$ )



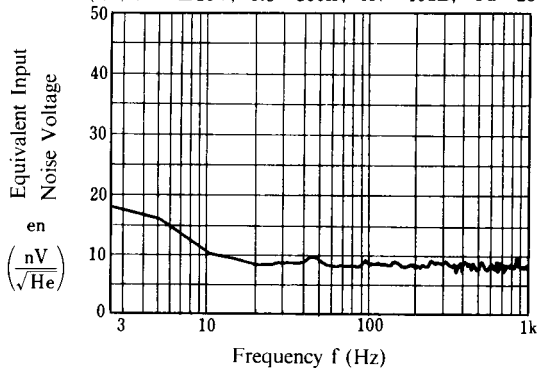
**Supply Current vs. Temperature**

( $V^+/V^- = \pm 15V$ )



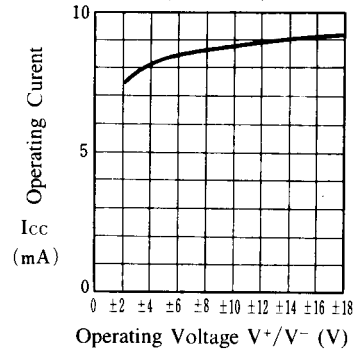
**Equivalent Input Noise Voltage vs. Frequency**

( $V^-/V^+ = \pm 15V$ ,  $R_s = 100\Omega$ ,  $A_v = 40\text{dB}$ ,  $T_a = 25^\circ\text{C}$ )



**Operating Current vs. Operating Voltage**

( $T_a = 25^\circ\text{C}$ )



**[CAUTION]**

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